MOSPEC

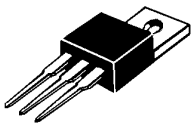
MBR30150CT

Schottky Barrier Rectifiers

Using the Schottky Barrier principle with a Refractory metal capable of high temperature operation metal. The properietary barrier technology allows for reliable operation up to 175℃ junction temperature. Typical application are in switching Mode Power Supplies such as adaptators, DC/DC convertes,free-wheeling and polarity protection diodes.

SCHOTTKY BARRIER RECTIFIERS

30 AMPERES
150 VOLTS

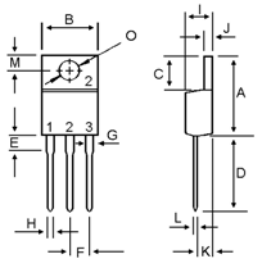


TO-220AB

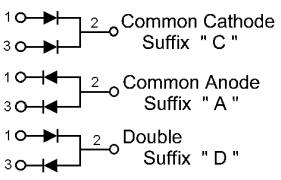
Features

- ＊Low Forward Voltage.
- ＊Low Switching noise.
- ＊High Current Capacity
- ＊Guarantee Reverse Avalanche.
- ＊Guard-Ring for Stress Protection.
- ＊Low Power Loss & High efficiency.
- ＊175℃ Operating Junction Temperature
- ＊Low Stored Charge Majority Carrier Conduction.
- ＊Plastic Material used Carries Underwriters Laboratory Flammability Classification 94V-O

＊*In compliance with EU RoHs 2002/95/EC directives*



DIM	MILLIMETERS	
	MIN	MAX
A	14.68	15.32
B	9.78	10.42
C	5.02	6.52
D	13.06	14.62
E	3.57	4.07
F	2.42	2.66
G	1.12	1.36
H	0.72	0.96
I	4.22	4.98
J	1.14	1.38
K	2.20	2.98
L	0.33	0.55
M	2.48	2.98
O	3.70	3.90



MAXIMUM RATINGS

Characteristic	Symbol	MBR30150CT	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V_{RRM} V_{RWM} V_R	150	V
RMS Reverse Voltage	$V_{R(RMS)}$	105	V
Average Rectifier Forward Current (per diode) Total Device (Rated V_R), T_C=125℃	$I_{F(AV)}$	15 30	A
Peak Repetitive Forward Current (Rate V_R, Square Wave, 20kHz)	I_{FM}	30	A
Non-Repetitive Peak Surge Current (Surge applied at rate load conditions halfware, single phase, 60Hz)	I_{FSM}	250	A
Operating and Storage Junction Temperature Range	T_J , T_{stg}	-65 to +175	℃

THERMAL RESISTANCES

Typical Thermal Resistance junction to case (per device)	$R_{\theta jc}$	3.0	℃/w

ELECTRIAL CHARACTERISTICS

Characteristic	Symbol	Min.	Typ	Max.	Unit
Maximum Instantaneous Forward Voltage (per diode)	V_F				V
(I_F =15 Amp T_C = 25℃)		--	0.82	0.95	
(I_F =15 Amp T_C = 125℃)		--	0.74	0.77	
Maximum Instantaneous Reverse Current	I_R				mA
(Rated DC Voltage, T_C = 25℃)		--	--	0.01	
(Rated DC Voltage, T_C = 125℃)		--	15	20	

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FIG-1 FORWARD CURRENT DERATING CURVE

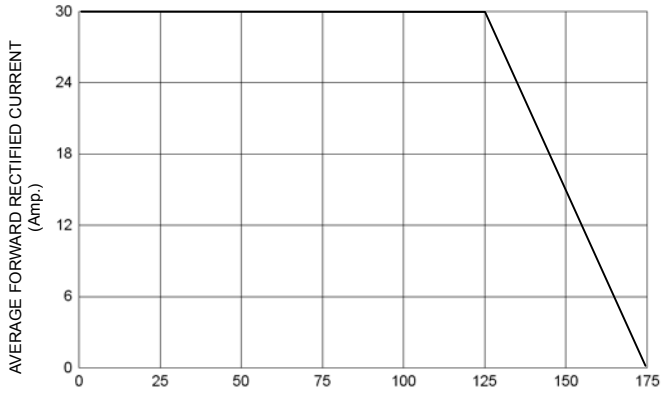


FIG-2 TYPICAL FORWARD CHARACTERISITICS

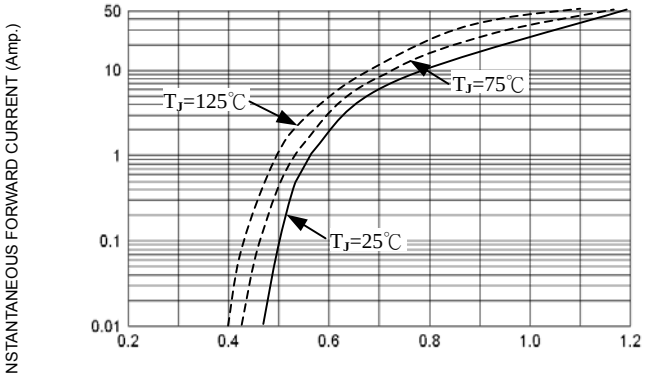


FIG-3 TYPICAL REVERSE CHARACTERISTICS

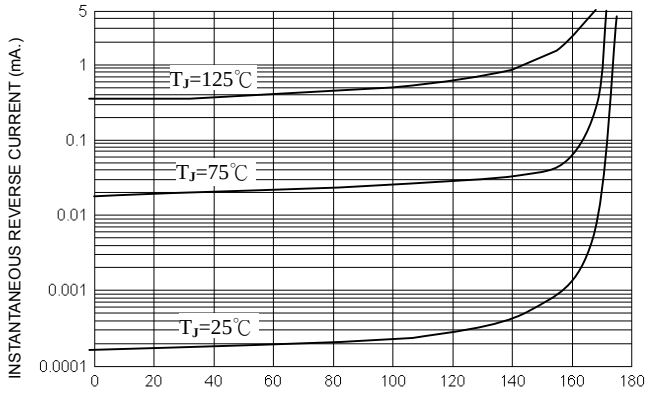


FIG-4 TYPICAL JUNCTION CAPACITANCE

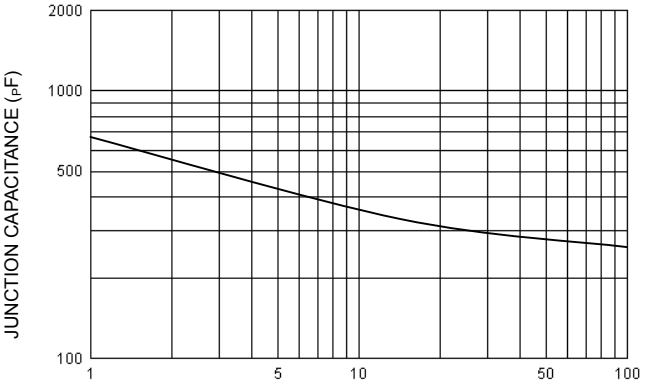
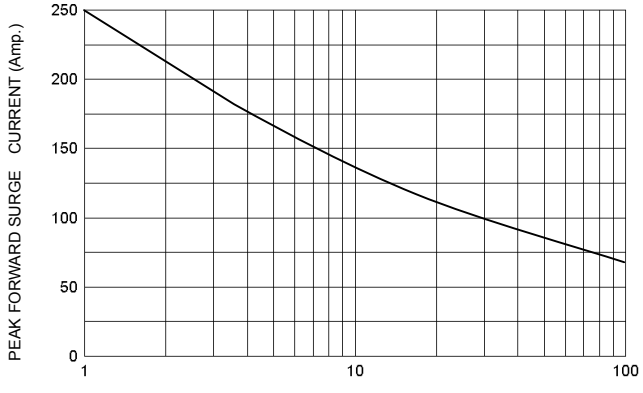


FIG-5 PEAK FORWARD SURGE CURRENT



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